

Agilent HLMP-CExx T-1 3/4 (5 mm) Precision Optical Performance InGaN Bluish-Green LED Lamps

Data Sheet



Description

These high intensity bluish-green LEDs are based on InGaN material technology. InGaN is the most efficient and cost effective material for LEDs in the blue and green region of the spectrum. The 505 nm typical dominant wavelength matches international specifications for green traffic signals.

These LED lamps are untinted, nondiffused, T-1 3/4 packages incorporating second generation optics producing well defined spatial radiation patterns at specific viewing cone angles.

These lamps are made with an advanced optical grade epoxy, offering superior temperature and moisture resistance in outdoor signal and sign applications. The package epoxy contains both UV-a and UV-b inhibitors to reduce the effects of long term exposure to direct sunlight.

These lamps are available in three viewing angle options and two package options to give the designer flexibility with optical design and device mounting.

Features

- Smooth, consistent spatial radiation patterns
- High luminous output
- Viewing angles 15°, 23°, and 30°
- Superior resistance to moisture

Benefits

- Viewing angles match traffic signal requirements
- Superior performance in outdoor environments
- Suitable for autoinsertion onto PC boards

Applications

- Traffic signals
- Railroad signals
- Commercial outdoor signs
- Automotive interior lights

CAUTION: HLMP-CExx LEDs are Class 1 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Agilent Application Note AN-1142 for additional details.



Agilent Technologies

Device Selection Guide

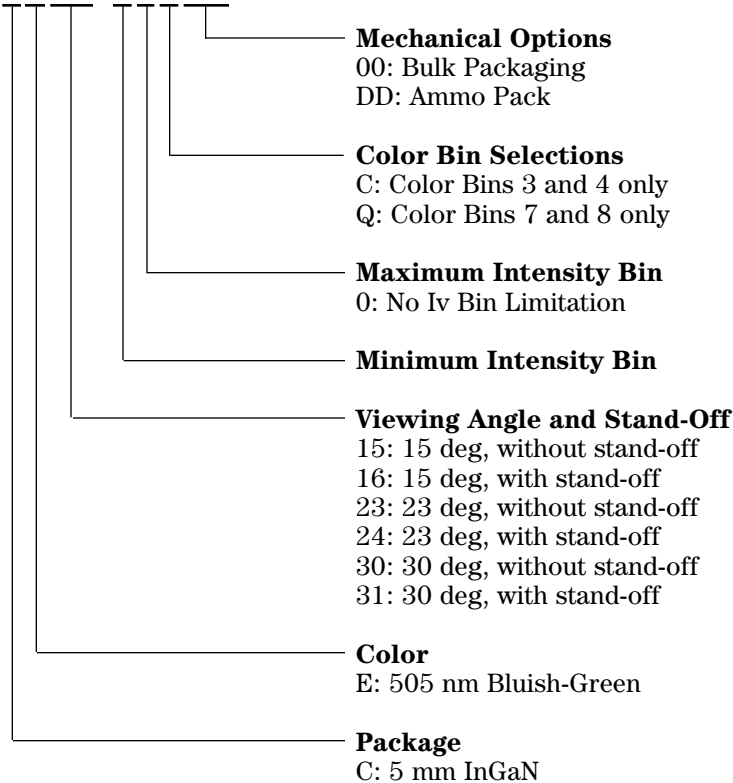
Part Number	Color and Dominant Wavelength λ_d Typ. (nm)	Viewing Angle $2\theta_{1/2}$ Typ. (deg)	Luminous Intensity I_v (mcd) at 20 mA		Stand-Off
			Min.	Max.	
HLMP-CE15-TWC00	505	15	2170	8300	No
HLMP-CE16-TWC00	505	15	2170	8300	Yes
HLMP-CE23-SVC00	505	23	1650	6300	No
HLMP-CE23-SVQ00	505	23	1650	6300	No
HLMP-CE24-SVC00	505	23	1650	6300	Yes
HLMP-CE24-SVQ00	505	23	1650	6300	Yes
HLMP-CE30-QTC00	505	30	1000	3700	No
HLMP-CE30-QTQ00	505	30	1000	3700	No
HLMP-CE31-QTC00	505	30	1000	3700	Yes
HLMP-CE31-QTQ00	505	30	1000	3700	Yes

Notes:

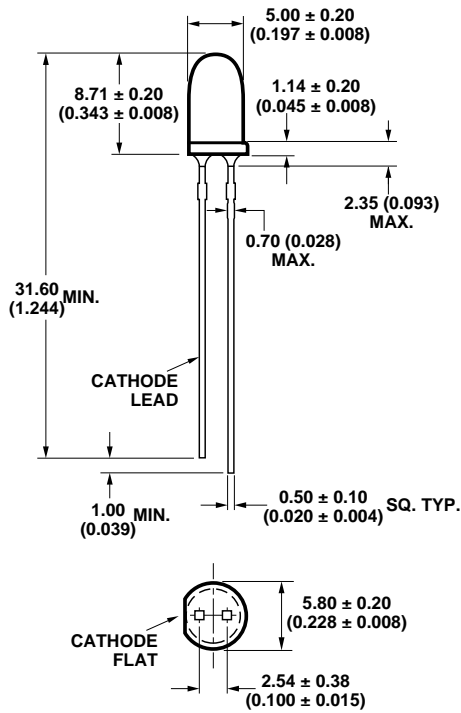
1. The luminous intensity is measured on the mechanical axis of the lamp package.
2. The optical axis is closely aligned with the package mechanical axis.
3. The dominant wavelength, λ_d , is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.
4. All InGaN LEDs represented here are IEC825 Class 2. See Application Brief 1-009 and 1-015 for details.

Part Numbering System

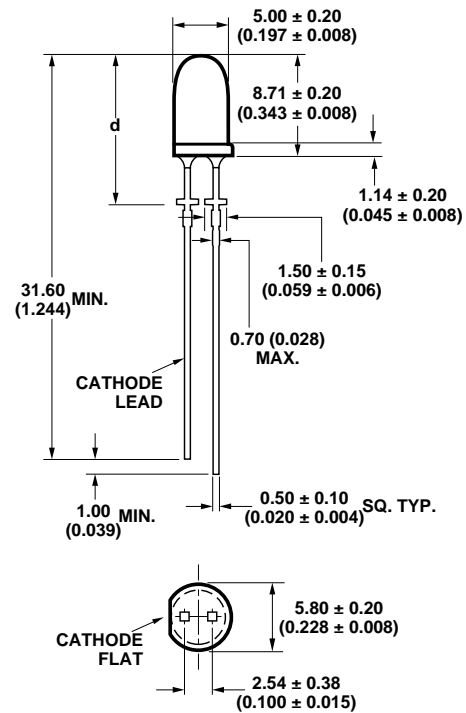
HLMP - X X X X - X X X X X



Package Dimensions



HLMP-CE15, HLMP-CE23, and HLMP-CE30



HLMP-CE16, HLMP-CE24, and HLMP-CE31

HLMP-CE16	HLMP-CE24	HLMP-CE31
d = 12.6 ± 0.18 (0.496 ± 0.007)	d = 12.40 ± 0.25 (0.488 ± 0.010)	d = 11.96 ± 0.25 (0.471 ± 0.010)

Notes:

1. Dimensions in mm.
2. Tolerance ±0.1 mm unless otherwise noted.

Absolute Maximum Ratings at T_A = 25°C

Parameter	Value	Units
DC Forward Current ^[1]	30	mA
Peak Forward Current	100	mA
Average Forward Current	30	mA
Power Dissipation	120	mW
Reverse Voltage (I _R = 100 μA)	5	V
LED Junction Temperature	130	°C
Operating Temperature Range	-40 to +80	°C
Storage Temperature Range	-40 to +100	°C

Note:

1. Derate linearly as shown in Figure 4 for temperatures above 50°C.

Electrical/Optical Characteristics at T_A = 25°C

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Forward Voltage	V _F		3.8	4.0	V	I _F = 20 mA
Reverse Voltage	V _R	10				I _R = 100 μA
Capacitance	C		40		pF	V _F = 0, f = 1 MHz
Thermal Resistance	Rθ _{J-PIN}		240		°C/W	LED Junction-to-Cathode Lead
Dominant Wavelength	λ _d		505		nm	I _F = 20 mA
Peak Wavelength	λ _{PEAK}		502		nm	Peak of Wavelength of Spectral Distribution at I _F = 20 mA
Spectral Halfwidth	Δλ _{1/2}		35		nm	Wavelength Width at Spectral Distribution Power Point at I _F = 20 mA
Luminous Efficacy	η _v		350		lm/W	Emitted luminous power/ Emitted radiant power

Notes:

1. The dominant wavelength, λ_d, is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.
2. The radiant intensity, I_e in watts per steradian, may be found from the equation I_e = I_v/η_v, where I_v is the luminous intensity in candelas and η_v is the luminous efficacy in lumens/watt.

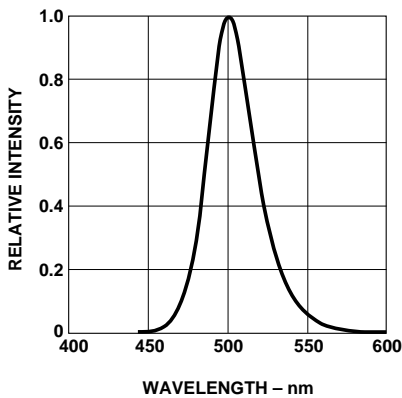


Figure 1. Relative intensity vs. wavelength.

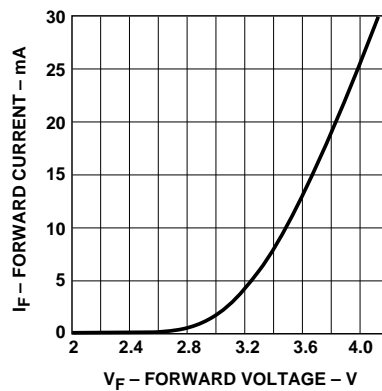


Figure 2. Forward current vs. forward voltage.

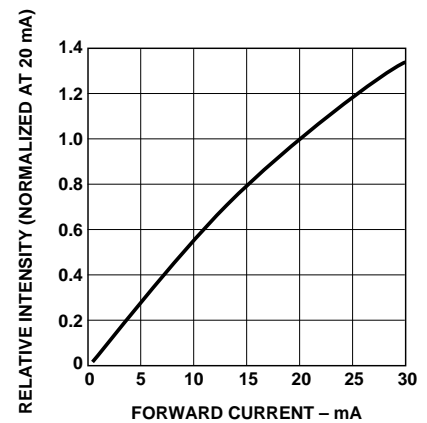


Figure 3. Relative luminous intensity vs. forward current.

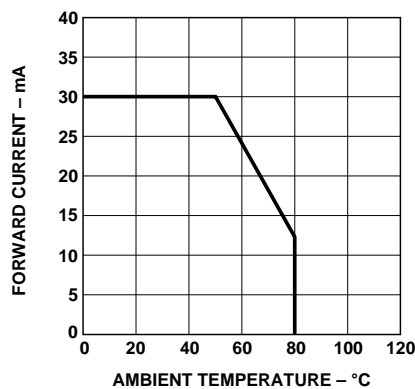


Figure 4. Maximum forward current vs. ambient temperature.

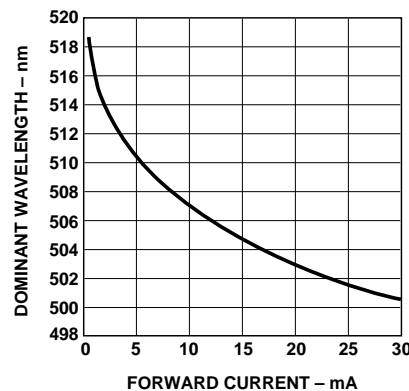


Figure 5. Color vs. forward current.

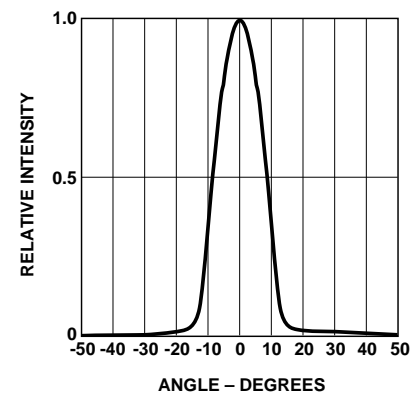


Figure 6. Spatial radiation pattern - 15° lamps.

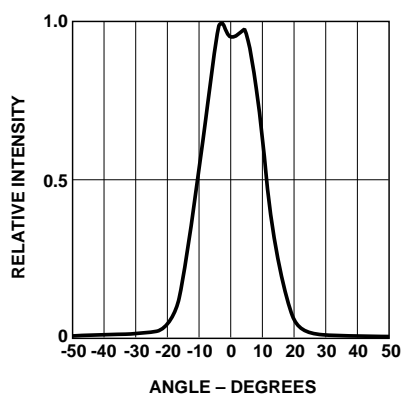


Figure 7. Spatial radiation pattern – 23° lamps.

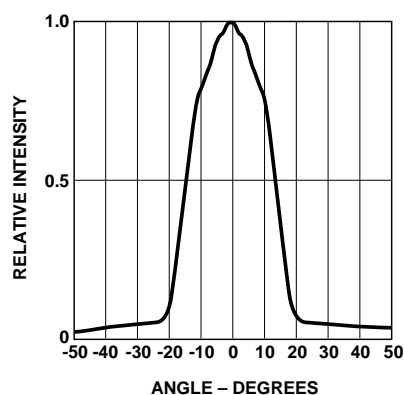


Figure 8. Spatial radiation pattern – 30° lamps.

Intensity Bin Limits (mcd at 20 mA)

Bin Name	Min.	Max.
P	880	1150
Q	1150	1500
R	1500	1900
S	1900	2500
T	2500	3200
U	3200	4200
V	4200	5500
W	5500	7200
X	7200	9300

Tolerance of each minimum and maximum = $\pm 15\%$.

Color Bin Limits (nm at 20 mA)

Bin Name	Min.	Max.
3	500	505
4	505	510
7	498	503
8	503	508

Tolerance for each minimum and maximum = ± 2 nm.

Note:

Bin categories are established for classification of products. Products may not be available in all bin categories. Please contact your Agilent representative for information on currently available bins.

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October 11, 2001
Obsoletes 5988-0932EN
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